

Technical documentation



Support & training

**[DRV2700](https://www.ti.com/product/DRV2700)** [SLOS861C](https://www.ti.com/lit/pdf/SLOS861) – MARCH 2015 – REVISED JANUARY 2023

# **DRV2700 Industrial Piezo Driver With Integrated Boost Converter**

### **1 Features**

<span id="page-0-0"></span>**TEXAS** 

**INSTRUMENTS** 

- 100-V Boost or 1-kV Flyback Configuration
- ±100-V Piezo Driver in Boost + Amplifier Configuration
	- 4 GPIO-Adjustable Gains
	- Differential or Single-Ended Output
	- Low-Voltage Control
	- AC and DC Output Control
- 0 to 1-kV Piezo Driver in Flyback Configuration
	- Low-Voltage Control
	- AC and DC Output Control
- Integrated Boost or Flyback Converter
	- Adjustable Current-Limit
	- Integrated Power FET and Diode
- Fast Startup Time of 1.5 ms
- Wide Supply-Voltage Range of 3.3 to 5.5 V
- 4-mm × 4-mm × 0.9-mm VQFN package
- 1.8-V Compatible Digital Pins
- Thermal Protection

### **2 Applications**

- Piezo Positioning Actuators
- Piezo Sounder Driver
- Piezo Inkjet Printer
- Piezo Transducers
- Piezoelectric Micropumps

### **3 Description**

The DRV2700 device is a single-chip piezo driver with an integrated 105-V boost switch, integrated power diode, and integrated fully-differential amplifier. This versatile device is capable of driving both high-voltage and low-voltage piezoelectric loads. The input signal can be either differential or single-ended and AC or DC coupled. The DRV2700 device supports four GPIO-controlled gains: 28.8 dB, 34.8 dB, 38.4 dB, and 40.7 dB.

The boost voltage is set using two external resistors. The voltage applied to the switch pin (SW) and the VDD pin have been sepearted to support independant batteries. The boost current-limit is programmable through the  $R_{(REXT)}$  resistor. The boost converter architecture allows the user to optimize the DRV2700 circuit for a given inductor based on the desired performance requirements. Additionally, this boost converter is based on a hysteretic architecture to minimize switching losses and therefore increase efficiency.

A typical startup time of 1.5 ms makes the DRV2700 device an ideal piezo driver for coming out of sleep quickly. Thermal overload protection prevents the device from damage when overdriven.

**Device Information** 



(1) For all available packages, see the orderable addendum at the end of the datasheet.



**Simplified Schematic**



## **Table of Contents**





### **4 Revision History**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.



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### **5 Pin Configuration and Functions**



NC – no internal connection

#### **Figure 5-1. RGP Package 20-Pin VQFN With Exposed Thermal Pad Top View**



### **Pin Functions**

(1)  $I = Input, O = Output, I/O = Input and output, P = Power$ 



# <span id="page-3-0"></span>**6 Specifications**

### **6.1 Absolute Maximum Ratings**

Over operating free-air temperature range (unless otherwise noted)



### **6.2 ESD Ratings**



(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### **6.3 Recommended Operating Conditions**



(1) Gains are optimized for a 1.8-V peak input

### **6.4 Thermal Information**



(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953.](https://www.ti.com/lit/pdf/SPRA953)

### <span id="page-4-0"></span>**6.5 Electrical Characteristics**





### **6.6 Switching Characteristics**

 $\rm V_{DD}$  = 3.6 V, T<sub>A</sub> = 25°C, V<sub>OUT(PP)</sub> = V<sub>OUT+</sub> – V<sub>OUT–</sub> = 200 V, C<sub>(LOAD)</sub> = 47 nF, G<sub>(AMP)</sub> = 40 dB, L = 4.7 µH (unless otherwise noted)





### <span id="page-5-0"></span>**6.7 Typical characteristics**

 $V_{DD}$  = 3.6 V, R<sub>(REXT)</sub> = 7.5 kΩ, L = 4.7 µH, differential input, 100-nF DC blocking capacitors on IN±





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### <span id="page-9-0"></span>**7 Detailed Description**

### **7.1 Overview**

The DRV2700 device is a single-chip piezo driver with an integrated 105-V boost switch, integrated power diode, and integrated fully-differential amplifier. This versatile device is capable of driving both high-voltage and low-voltage piezo loads. The input signal can be either differential or single-ended. The DRV2700 device supports four GPIO-controlled gains: 28.8 dB, 34.8 dB, 38.4 dB, and 40.7 dB.

The boost voltage is set using two external resistors. The boost current-limit is programmable through the  $R_{(REXT)}$  resistor. The boost converter architecture does not allow the demand on the supply current to exceed the limit set by the  $R_{(REXT)}$  resistor; therefore, allowing the user to optimize the DRV2700 circuit for a given inductor based on the desired performance requirements. Additionally, this boost converter is based on a hysteretic architecture to minimize switching losses and therefore increase efficiency.

A typical start-up time of 1.5 ms makes the DRV2700 device an ideal piezo driver for fast responses. Thermal overload protection prevents the device from damage when overdriven.

### **7.2 Functional Block Diagram**



<span id="page-10-0"></span>

#### **7.3 Feature Description**

#### **7.3.1 Boost Converter and Control Loop**

The DRV2700 device creates a boosted supply rail with an integrated DC-DC converter that can go up to 105 V. The switch-mode power supplies have a few different sources of losses. When boosting to very high voltages, the efficiency begins to degrade because of these losses. The DRV2700 device has a hysteretic boost design to minimize switching losses and therefore increase efficiency. A hysteretic controller is a self-oscillation circuit that regulates the output voltage by keeping the output voltage within a hysteresis window set by a reference voltage regulator and, in this case, the current-limit comparator. Hysteretic converters typically have a larger ripple as a trade off because of the minimized switching. This ripple may vary depending on the output capacitor and load. The power FET and power diode of the boost converter are both integrated within the device to provide the required switching while minimizing external components. Additionally, the boost voltage output (BST) can be easily fed into the high-voltage amplifier through the adjacent pin (PVDD) to help minimize routing inductance and resistance on the board.

#### **7.3.2 High-Voltage Amplifier**

When using the high-voltage amplifier in conjunction with the boost converter, the PVDD pin is located next to the BST pin to immediately feed the high voltage signal back into the device to power the amplifier. The DRV2700 device was designed as a differential amplifier. A major benefit of the fully differential amplifier is the improved common-mode rejection ratio (CMRR) over single-ended input amplifiers. The increased CMRR of the differential amplifier reduces sensitivity-to-ground offset that is related noise injection which is important in low-noise systems.

The high-voltage amplifier can be used in a single-ended DC input configuration to provide a DC output on the OUT+ and OUT– pins. The amplifier is very linear across the full voltage range and by using a DAC (digital-to-analog converter) input, the output can be controlled with very good granularity.

Precautions must be taken into thermal concerns of this amplifier because high frequencies, voltage, and capacitive load combinations can overheat the device. See the *[Section 8.2.1.2.1](#page-13-0)* section for a general guideline.

#### **7.3.3 Fast Start-Up (Enable Pin)**

The DRV2700 device features a fast startup time, which is beneficial for the device come out of shutdown very quickly. When the EN pin transitions from low to high, the boost supply is turned on, the input capacitor is precharged to  $V_{DD}$  / 2, and the amplifier is enabled in a 1.5 ms (typical) total start-up time.

When AC coupled with larger input capacitors, the input can require additional time to charge up to  $V_{DD}$  / 2. Because the charging current on the input capacitors are not ensured to be exactly the same, a non-zero differential value can exist during startup. Although this differential output voltage (voltage pop) during startup is not specified, it should be fairly small and not exceed 2 V.

#### **7.3.4 Gain Control**

The DRV2700 device has programmable gains through the GAIN[1:0] bits. [Table 8-1](#page-13-0) lists the gain from IN+ or IN– to OUT+ or OUT–.



#### **Table 7-1. Programmable Gains**

The gains are optimized to achieve approximately 50  $V_{PP}$ , 100  $V_{PP}$ , 150  $V_{PP}$ , or 200  $V_{PP}$  at the output without clipping from a 1.8-V peak source of a single-ended input signal.

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#### <span id="page-11-0"></span>**7.3.5 Adjustable Boost Voltage**

The output voltage of the integrated boost converter is adjusted by a resistive feedback divider between the boost output voltage (BST) and the feedback pin (FB). The boost voltage should be programmed to a value greater than the maximum peak signal voltage that the user expects to create with the DRV2700 amplifier. Lower boost voltages achieve better system efficiency and therefore should be used when lower amplitude signals are applied. The minimum boost voltage that is required should be used to save on not only power but also heat dissipation. The maximum allowed boost voltage is 105 V.

#### **7.3.6 Adjustable Boost Current-Limit**

The current-limit of the boost switch is adjusted through a resistor to ground placed on the REXT pin. In order to protect the device, the REXT pin value should remain between 7.5 kΩ and 32.5 kΩ as shown in [Figure 6-20.](#page-8-0) To avoid damage to both the inductor and the DRV2700 device, the programmed current-limit must be less than the rated saturation limit of the inductor selected by the user. If the combination of the programmed limit and inductor saturation is not high enough, then the output current of the boost converter is not high enough to regulate the boost output voltage under heavy load conditions. This lower output current causes the boosted rail to sag which can possibly cause distortion of the output waveform.

#### **7.3.7 Internal Charge Pump**

The DRV2700 device has an integrated charge pump to provide gate drive for internal nodes. The output of this charge pump is placed on the VPUMP pin. An X5R or X7R storage capacitor with a value of 0.1 µF and a voltage rating of 10 V or greater must be placed at this pin for proper operation. This pin and voltage should not be used as an external reference or driver.

#### **7.3.8 Thermal Shutdown**

The DRV2700 device contains an internal temperature sensor that shuts down both the boost converter and the amplifier when the temperature threshold is exceeded. When the die temperature falls below the threshold, the device restarts operation automatically as long as the EN pin is high. Continuous operation of the DRV2700 device can cause the device to heat up if proper precautions and operating ranges are not followed. The thermal shutdown function protects the DRV2700 device from damage when overdriven, but usage models which drive the DRV2700 device into thermal shutdown should always be avoided.

#### **7.4 Device Functional Modes**

Although a high-voltage amplifier can be used in a number of ways, the DRV2700 device was intended for two main configurations which are boost + amplifier mode and flyback mode.

#### **7.4.1 Boost + Amplifier Mode**

In the boost + amplifier mode configuration, the boost converter is used in a boost configuration with a single inductor. The boost output (BST) is then fed into the high-voltage amplifier (PVDD) to drive the outputs. This configuration supports the boost converter up to 100  $V_P$  and the amplifier to drive 200  $V_{PP}$  or 0 to 100  $V_P$ . The *[Section 8.2](#page-12-0)* section describes the various implementations of this mode.

#### **7.4.2 Flyback Mode**

In the flyback mode configuration, the boost converter is used in a flyback configuration which allows the boost converter to drive the output to even higher voltages. For example, with a 1:10 turn ratio of the transformer, the transformer can turn the 100 V on the SW node into 1 kV on the high-voltage output. [Figure 8-16](#page-24-0) shows a basic circuit diagram.

<span id="page-12-0"></span>

### **8 Application and Implementation**

#### **Note**

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

#### **8.1 Application Information**

The DRV2700 is intended to drive piezo loads. This includes: capacitive loads, piezo sounders, piezo valves, piezo positioning actuators, piezo micropumps, piezo polymers and more.

#### **8.2 Typical Applications**

#### **8.2.1 AC-Coupled DAC Input Application**

The AC-coupled DAC input circuit shown in Figure 8-1 is typically used in piezo speaker applications. ACcoupling the DRV2700 device allows the device to only amplify the differential portions of the input which minimizes the common-mode amplification. Because a digitized AC signal is provided from an external source, such as a microcontroller, an input filter is not required. However, a low-pass filter can be added to minimize the harmonics of the digitized waveform.



**Figure 8-1. AC-Coupled DAC Input**



#### <span id="page-13-0"></span>*8.2.1.1 Design Requirements*

For this design example, use the parameters listed in Table 8-1 as the input parameters.



#### **Table 8-1. Design Parameters**

#### *8.2.1.2 Detailed Design Procedure*

To design the entire system follow the design procedure listed in the following sections.

#### **8.2.1.2.1 Piezo Load Selection**

Several key specifications must be considered when selecting a piezo actuator such as dimensions, blocking force, and displacement. However, the key electrical specifications from the driver perspective are voltage rating and capacitance. The DRV2700 device operating in boost + amplifier mode can drive a variety of capacitances, frequencies, and voltages. However to extend the range in one specification can decrease the range of another specification. For example, if driving audio tones around 1 kHz, a lower capacitance piezo or lower driving voltage may be required. Figure 8-2 shows a general guide to selecting the proper parameters.



**Figure 8-2. Maximum Frequency versus Maximum Voltage for Different Load Capacitances**

Based on the design example, if the output voltage must be  $\pm 60 \, V_{\text{OUT}}$  to 2 kHz, then the piezo capacitance must be less than 100 nF. For ease of calculation, use a piezo load capacitance of 25 nF.



#### **8.2.1.2.2 Programming The Boost Voltage**

The boost or flyback output voltage is programmed by an external network as shown in Figure 8-3.



**Figure 8-3. External Network**

Depending on which configuration or mode is used in the system, use Equation 1 to calculate the output voltage.

$$
V_{\text{BST}} = V_{\text{FB}} \left( 1 + \frac{R_{(\text{FB1})}}{R_{(\text{FB2})}} \right) \qquad V_{\text{HV}} = V_{\text{FB}} \left( 1 + \frac{R_{(\text{FB1})}}{R_{(\text{FB2})}} \right) - \left( \frac{R_{(\text{FB1})}}{R_{(\text{FB2})}} \right) V_{\text{OP}}
$$
\n
$$
\text{Boost} + \text{Amplifier} \qquad \text{Flyback}
$$
\n
$$
\text{Configuration} \qquad \text{Configuration} \qquad (1)
$$

where

•  $V_{FB} = 1.30 V$ 

•  $V_{OP}$  =  $V_{OL}$  of the operational amplifier (op amp). Typically this can be approximated to 0 V.

The BST pin should be programmed to a value 5-V greater than the largest peak voltage in the system expected to allow adequate amplifier headroom. Because the programming range for the boost voltage extends to 105 V, the leakage current through the resistor divider becomes significant. TI recommends that the sum of the resistance of R<sub>(FB1)</sub> and R<sub>(FB2)</sub> be greater than 500 kΩ.

The flyback mode configuration may require filtering capacitors to go along with the feedback network to increase the performance at low and high frequencies. Because the charge storage is inversely proportional to the capacitance, use Equation 2 to calculate the values of the capacitors. In general, select a value of 22 pF for  $C_{(FB1)}$ .

For this design example, because the value of  $V_{\text{PP}}$  must be negative, the boost + amplifier configuration must be used. Additionally, because the value of V<sub>BST</sub> must be 5 V more than V<sub>P</sub>, V<sub>BST</sub> is set to 65 V. Using Equation 1, the feedback resistors can be found such that  $R_{FB1}$  = 49 ×  $R_{FB2}$ . Because the total resistance must be greater than 500 kΩ, R<sub>FB1</sub>= 735 kΩ and R<sub>FB2</sub>= 15 kΩ.

$$
\frac{R_{\text{(FB1)}}}{R_{\text{(FB2)}}}=\frac{C_{\text{(FB2)}}}{C_{\text{(FB1)}}}
$$

(2)

#### **Note**

When resistor values greater than 1 M $\Omega$  are used, PCB contamination causes boost voltage inaccuracy. Use caution when soldering large resistences, and clean the area when finished for best results.

#### **8.2.1.2.3 Inductor and Transformer Selection**

Inductor selection plays a critical role in the performance of the DRV2700 device. The range of recommended inductances is from 3.3 to 22 µH. In general, higher inductances within a given manufacturer's inductor series



(3)

have lower saturation current-limits and lower inductances have higher saturation current-limits. When a larger inductance is selected, the DRV2700 boost converter automatically runs at a lower switching frequency and incurs less switching losses. However, larger values of inductance may have higher ESR which increases the parasitic inductor losses. Because lower values of inductance generally have higher saturation currents, inductors with a lower value are a better choice when attempting to maximize the output current of the boost converter.

Another factor to consider for transformers is the winding ratio. In general, if a 200-V output is desired then, because the SW node can boost up to 100 V, a transformer of 1:2 (100 V:200 V) is the minimum required winding. However, selecting a slightly higher winding ratio to ensure that the 100 V on the primary side is not surpassed while trying to boost up to the desired voltage is good design practice.

For this design example, select an inductor of 3.3 µH with a saturation current of 1.5 A.

#### **8.2.1.2.4 Programing the Boost and Flyback Current-Limit**

The peak current drawn from the supply through the inductor is set solely by the  $R_{(REXT)}$  resistor. This peak current-limit is independent of the selected inductance value, but the inductor is capable of handling this programmed limit. Use Equation 3 to calculate the relationship between  $R_{(REXT)}$  and  $I_{(LIM)}$ .

$$
R_{(REXT)} = \left(K \frac{V_{ref}}{I_{(LIM)}}\right) - R_{(INT)}
$$

where

- $K = 10,500$
- $V_{ref}$  = 1.35 V
- $I_{(LIM)}$  is the desired peak current-limit through the inductor or transformer
- $R_{(INT)} = 60 \Omega$

For this design example, because the saturation current is 1.5 A, select 1 A for the  $I_{(LIM)}$  value. Using Equation 3, the value of R<sub>(EXT)</sub> is approximately 14 kΩ.

#### **8.2.1.2.5 Boost Capacitor Selection**

The boost output voltage is programmable as high as 105 V. A capacitor with a voltage rating of at least the boost output voltage must be selected. Because ceramic capacitors come in ratings of 100 V or 250 V, a 250-V rated 100-nF capacitor of the X5R or X7R type is recommended for the 105-V case. The selected capacitor should have a minimum working capacitance of at least 50 nF. If a smaller ripple on this node is required, then a larger capacitor should be selected. If using a differential output in the boost + amplifier configuration, then the ripple is canceled because it is prevelant on both the OUT+ and OUT– pins.

For this design example, a 100-nF capacitor was used.

#### **8.2.1.2.6 Pulldown FET and Resistors**

The pulldown FET and resistor are used to help speed up the drain the charge on the high-voltage output. Because the FET must be driven from a comparator, an NMOS FET must be used. During normal operation, the  $V_{DS}$  of the NMOS is subject to a any value from approximately 0 V when the FET is on, to the output on the flyback configuration (V<sub>(HV)</sub>) when the FET is off. Therefore, selecting a FET with a V<sub>DS</sub> breakdown higher than the maximum  $V_{HV}$  is required. Additionally, placing a resistor in series with this FET (on the drain side) to limit the current going through the FET is required. This resistor can be sized according to the maximum current allowed per the data sheet of the FET. As an additional measure, a resistor can be placed on the source side to protect the pulldown FET, such that when current flows through the resistor, it raises the source voltage and thereby lowers the  $V_{GS}$  and shuts the FET off.

Because this design example is using the boost + amplifier configuration, the pulldown FET and resistors are not required.



#### **8.2.1.2.7 Low-Voltage Operation**

The lowest gain setting is optimized for 50  $V_{PP}$  with a boost voltage of 30 V. Some applications may not require 50  $V_{\text{PP}}$ , therefore the designer may choose to program the boost converter as low as 15 V to improve efficiency. When using boost voltages lower than 30 V, consider using a boost capacitor and adjusting the full-scale input range First, to reduce boost ripple to an acceptable level, a 50-V rated, 0.22-µF boost capacitor is recommended. Second, the full-scale input range may require adjustment to avoid clipping. Generally, a 1.8-V single-ended PWM signal provides 50  $V_{PP}$  at the lowest gain. For example, if the boost voltage is set to 25 V for a 40  $V_{PP}$  full-scale output signal, the full-scale input range drops to 1.44 V for single-ended PWM inputs. An input voltage divider may be desired in this case if a 1.8-V I/O is used as a PWM source.

#### **8.2.1.2.8 Current Consumption Calculation**

Understanding how the voltage driven onto a piezo actuator relates to the current consumption from the power supply is useful. Modeling a piezo element as a pure capacitor is reasonably accurate. Use Equation 4 to calculate the current through a capacitor for an applied sinusoid.

$$
I_{Capacitor(Peak)} = 2\pi \times f \times C \times V_P
$$
\n(4)

- $f$  is the frequency of the sinusoid in hertz
- C is the capacitance of the piezo load in farads
- $V_P$  is the peak voltage

At the power supply, the actuator current is multiplied by the boost-supply ratio and divided by the efficiency of the boost converter as shown in Equation 5.

$$
I_{DD(Peak)} = 2\pi \times f \times C \times V_P \times \frac{V_{Boost}}{V_{DD} \times \mu_{Boost}}
$$
\n(5)

Substituting the design example values for the variables into Equation 5 and using a boost efficiency of 60%, yields a typical peak current from the power supply of 408 mA as shown in Equation 6.

$$
I_{DD(Peak)} = 2\pi \times 2 \text{ kHz} \times 25 \text{ nF} \times 60 \text{ V} \times \frac{65 \text{ V}}{5 \text{ V} \times 0.6} = 408 \text{ mA}
$$
 (6)

#### **8.2.1.2.9 Input Filter Considerations**

Depending on the quality of the source signal provided to the DRV2700 device, an input filter may be required. Some key factors to consider are whether the source is generated from a DAC or from PWM, and the out-ofband content generated. If proper anti-image rejection filtering is used to eliminate image components, the filter can possibly be eliminated depending on the magnitude of the out-of-band components. If PWM is used, at least a first-order RC filter is required. The PWM sample rate must be greater than 30 kHz to keep the PWM ripple from reaching the piezo element and dissipating unnecessary power. A second-order RC filter may be desirable to further eliminate out-of-band signal content to further drive down power dissipation and eliminate audible noise.

For this design example, to ensure higher harmonics of the input signal do not propagate into the device, use a low pass filter with a 3-dB point of 2 kHz. Refer to *DRV2700EVM High Voltage Piezo Driver Evaluation Kit*, [SLOU403,](https://www.ti.com/lit/pdf/SLOU403) to build this input filter network.

#### **8.2.1.2.10 Output Limiting Factors**

Because of the small size of the DRV2700 device, limiting factors must be considered. In each of the applications, four factors can affect the output. These factors include the following:

- Bandwidth of the amplifier
- Limited current
- Slew rate
- Thermal shutdown



Although some of these factors can appear at the same time, each of these factors are shown in the following figures to help the designer differentiate between each factor.



**Figure 8-4. Bandwidth and Limited Current**

The internal amplifier has an inherent bandwidth limitation on the order of 5 to 20 kHz depending on the gain settings. Although, this bandwidth limitation occurs primarily with a no-load condition or under a very small voltage swing, the output is essentially unable to drive to the expected output voltage because of a drop in the gain at that bandwidth. The internal boost converter can only support a limited amount of current. If for instance, the load was somewhat resistive as opposed to only capacitive, a situation could occur where the load requires additional current to pull the voltage up, however the boost converter cannot support it. This situation appears to be an out-of-regulation output voltage.



**Figure 8-5. Slew Rate and Thermal Shutdown**

As the output frequency increases, the slew rate increases. Because the boost converter can only support a certain amount of current based on the load capacitance, the sine wave begins to turn into more of a triangle wave.

Lastly, the device has a thermal shutdown feature for protection from damaging when the device begins to heat up because of power dissipation. When a load is primarily capacitance, the current leads the voltage (leading power factor). With a leading or lagging power factor, the maximum power does not occur at the maximum voltage or current. However the maximum power does occur at the phase crossing of these. This occurrence looks similar to the waveform in Figure 8-5, such that the output goes to 0 V and then start back up after it has cooled down below the internal threshold. [Figure 8-2](#page-13-0) shows a general guideline to staying below the maximum voltage and frequency based on the capacitance of the load.



#### **8.2.1.2.11 Startup and Shutdown Sequencing**

A simple startup sequence is employed to maintain smooth operation. If the sequence is not followed, unintended events my occur.

Use the following steps to startup the device in boost + amplifier mode:

- 1. Transition the DRV2700 enable pin from logic-low to logic-high.
- 2. Wait 2 ms to ensure that the DRV2700 circuitry is fully enabled and settled.
- 3. Provide a PWM, audio, or DAC source to be amplified through the DRV2700 device. When the input waveform is complete, continue to step 4.
- 4. Transition the DRV2700 enable pin from high to low.

Use the following steps to startup the device in flyback mode:

- 1. Set the processor output to 0 V to set the feedback network to such that  $V_{HV}$  = 0 V. This setting ensures that  $V_{HV}$  does not spike when the device is enabled.
- 2. Transition the DRV2700 enable pin from logic-low to logic-high.
- 3. Wait 2 ms to ensure that the DRV2700 circuitry is fully enabled and settled.
- 4. Begin and complete playback of the waveform from the processor. When the input waveform is complete, continue to step 4.
- 5. Transition the DRV2700 enable pin from high to low and power down the DAC source.

#### *8.2.1.3 Application Curves*



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#### **8.2.2 Filtered AC Coupled Single-Ended PWM Input Application**

The AC coupled single-ended PWM input is very similar to the application described in the *[Section 8.2.1](#page-12-0)* section, however because the input is a true PWM signal, a low-pass filter is highly recommended. Typically, a low cutoff frequency is desired to ensure the higher frequencies have been attenuated and are not amplified.



**Figure 8-12. Filtered AC Coupled Single-Ended PWM Input**



#### **8.2.3 DC-Coupled DAC Input Application**

The DC-coupled DAC input is used in applications when the user might need to drive the output at a constant DC level. A typical application for th the DC-coupled DAC input is for piezo pneumatic valves. A benefit to this application circuit is that all of the inputs, including power, are at a very low voltage while keeping the high-voltage piezo load separated. This feature allows easy implementation into systems and to help separate or isolate the high voltages loads from the critical controls.

Piezoelectric materials have a certain voltage that debias the piezo phenomenon. To prevent this debiasing from occurring, limit the input using a controlled input signal. As a backup measure, place a Zener diode to restrict the input.



**Figure 8-13. DC-Coupled DAC Input**



#### **8.2.4 DC-Coupled Reference Input Application**

The DC-coupled referenced to  $V_{DD}$  input is used in applications when the user might need to drive the output at a constant DC level in an on-off implementation. A typical application for this configuration is for piezo pneumatic valves. A benefit to this application circuit is that all of the inputs, including power, are at a very low voltage while keeping the high-voltage piezo load separated. Additionally, all that is required is the  $V_{DD}$  input. This feature allows easy implementation into systems and to help separate or isolate the high voltages loads from the critical controls.

As mentioned in the previous section, piezoelectric materials have a certain voltage that debias the piezo phenomenon. This configuration protects the piezo from negative voltages because the input is always positive.



**Figure 8-14. DC-Coupled Referenced Input**

This application circuit can also be altered to only use the boost as shown in [Figure 8-15.](#page-23-0) The benefits of altering this circuit is that it requires less components and has better power efficiency because no power is used in the amplifier. The drawback is that ripple occurs on the piezo element and the fall time of the output is longer because it is drained based on the RC time constant on the BST node.



<span id="page-23-0"></span>

**Figure 8-15. Boost Driving Piezo**

#### **8.2.5 Flyback Circuit**

The flyback circuit is intended for applications using piezo valves, piezo polymers, and other high-voltage loads. The previously listed applications go from ±100 V, however this circuit can go up to even higher voltages (1 kV for example) depending on the feedback network and maximum operating conditions of the external components. The input is controlled using PWM, a DAC, or a purely analog signal. Therefore, a proper input filter may be required as discussed in the previous application circuits.

The increased voltage range, however, comes at a price. As the output voltage increases, the capable output sourcing current is lowered. However, because most piezo loads require a small current for the holding or blocking force, the drop in current may not impact the performance of the application. [Figure 8-16](#page-24-0) shows a typical flyback circuit.

<span id="page-24-0"></span>



**Figure 8-16. Flyback Circuit**

The following sections shown in Figure 8-16 must be explained:

- Op-amp integrator
- Comparator and pulldown FET
- $C_{(HV)}$  value

The op-amp integrator shown at the bottom of the circuit in Figure 8-16, is used to control the output voltage. Because the input can be a PWM or DAC signal, it helps smooth out the input signal. Additionally, the output controls the virtual ground of the feedback network. For example, when the output of the integrator is equal to  $V_{OL}$  (approximately 0 V), the current through  $R_{(FB2)}$  is at the maximum and therefore increase the current (and voltage) on R<sub>(FB1)</sub> which raises the voltage across the piezo load. Likewise, as the output voltage of the integrator increases, it then decreases the current through  $R_{(FB2)}$  and therefore decreases the voltage on  $R_{(FB1)}$ , which lowers the voltage across the piezo load.

The comparator and pulldown FET are used to drain the charge on the high-voltage output. Because a high resistance (or low current) is desired through for the feedback network, the RC-time constant of draining charge can be very long. To help with this long RC-time constraint, the comparator and pulldown FET are added to drain charge when  $V_{FB}$  >  $V_{ref}$  which adds a low resistance in parallel and therefore lowers the RC time constant. Ensure that this pulldown network can support the voltage and the current. As shown in [Figure 8-9](#page-19-0) and [Figure](#page-19-0) [8-10,](#page-19-0) the pulldown allows for better regulation and faster stopping time.

Lastly, the C<sub>(HV)</sub> value is determined by the system. A value of  $>1$ -nF total capacitance is required on the high-voltage node for proper regulation. This total capacitance is the combination of the piezo load and the onboard  $C_{(HV)}$ .

#### **Note**

As the capacitance increases, the voltage ripple on the output decreases. However, this decrease in ripple also slows down the startup or slew rate on the output. Ensure that the  $C_{(HV)}$  and the piezo load can support the high voltage across  $C_{(HV)}$  and the load.

#### **8.3 System Example**

To use the DRV2700 in a system, all that is required is a controller for the input signal and digital control, power management to provide power to the device, and a high-voltage load. [Figure 8-17](#page-25-0) shows a typical system



<span id="page-25-0"></span>diagram using the DRV2700 device. Because most systems already include some type of controller and power management, the DRV2700 device can easily be added to an existing system.



**Figure 8-17. DRV2700 System Diagram**

<span id="page-26-0"></span>

### **9 Power Supply Recommendations**

The recommended voltage supply range for the DRV2700 device is 3.3 to 5.5 V. For proper operation, place a 0.1-µF low-equivalent series resistance (ESR) supply-bypass capacitor of X5R or X7R type near the V<sub>DD</sub> pin. This bypass capacitor should have a voltage rating of at least 10 V. The internal charge pump requires a 0.1-µF capacitor of X5R or X7R type with a voltage rating of 10 V or greater to be placed between the PUMP pin and ground for proper operation and stability. Do not use the charge pump as a voltage source for any other devices.



### <span id="page-27-0"></span>**10 Layout**

### **10.1 Layout Guidelines**

The following layout guidelines are provided for circuit performance only. The user is solely responsible for compliance with any industry standard requirements and other legal, regulatory, and safety-related requirements concerning its applications and products, as well as use of the DRV2700 device in such applications or products.

#### **10.1.1 Boost + Amplifier Configuration Layout Considerations**

To achieve ideal device performance, use of the thermal footprint outlined by this data sheet is recommended. See the land pattern diagram in the *[Section 12](#page-29-0)* section for exact dimensions. The thermal pad of the DRV2700 device must be soldered directly to the thermal pad on the printed circuit board (PCB). The thermal pad of the PCB must be connected to the ground net with thermal vias to any existing backside or internal copper ground planes. Connection to a ground plane on the top layer near the corners of the device is also recommended.

Additionally to help minimize crosstalk between the FB voltage and the SW signal, keep the boost programming resistors ( $R_{FB1}$  and  $R_{FB2}$ ) as close as possible to the FB pin of the DRV2700 device. Routing this trace underneath the middle of the inductor is also helpful. If possible, provide a grounding plane between the two signals.

Lastly, keep the BST trace and plane as large as possible to help minimize the resistance and inductance.

#### **10.1.2 Flyback Configuration Layout Considerations**

To achieve ideal device performance, use of the thermal footprint outlined by this data sheet is recommended. See the land pattern diagram in the *[Section 12](#page-29-0)* section for exact dimensions. The thermal pad of the DRV2700 device must be soldered directly to the thermal pad on the PCB. The thermal pad of the PCB must be connected to the ground net with thermal vias to any existing backside or internal copper ground planes. Connection to a ground plane on the top layer near the corners of the device is also recommended.

Additionally, minimizing the capacitance on the SW node is very important. Minimizing this capacitance is accomplished by placing the transformer very close to the SW pin and by removing the ground plane beneath the transformer pads.

### **10.2 Layout Example**



**Figure 10-1. DRV2700 Boost + Amplifier Layout Example**





**Figure 10-2. DRV2700 Flyback Layout Example**



### <span id="page-29-0"></span>**11 Device and Documentation Support**

### **11.1 Documentation Support**

#### **11.1.1 Related Documentation**

For related documentation see the following:

*DRV2700EVM High Voltage Piezo Driver Evaluation Kit*, [SLOU403](https://www.ti.com/lit/pdf/SLOU403)

#### **11.2 Trademarks**

All trademarks are the property of their respective owners.

### **12 Mechanical, Packaging, and Orderable Information**

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



### **PACKAGING INFORMATION**



**(1)** The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures. "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

**(3)** MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

**(4)** There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

**(5)** Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

**(6)** Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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# **PACKAGE OPTION ADDENDUM**

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**TEXAS** 

#### **TAPE AND REEL INFORMATION**

**ISTRUMENTS** 





#### **QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**







# **PACKAGE MATERIALS INFORMATION**

www.ti.com 25-Feb-2023



\*All dimensions are nominal



# **GENERIC PACKAGE VIEW**

# **RGP 20 VQFN - 1 mm max height**

**4 x 4, 0.5 mm pitch** VERY THIN QUAD FLATPACK



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



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